



Standard Rectifier

$V_{RRM} = 1200\text{ V}$

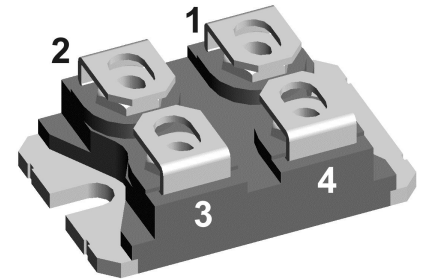
$I_{FAV} = 2 \times 60\text{ A}$

$V_F = 1.22\text{ V}$

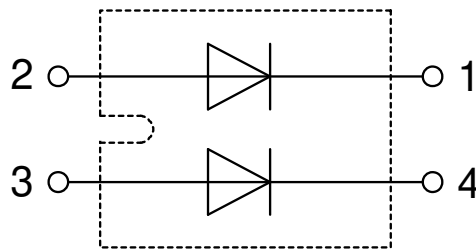
Parallel legs

Part number

DSI2x55-12A



Backside: isolated



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

- Diode for main rectification
- For single and three phase bridge configurations

Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper internally DCB isolated
- Advanced power cycling

Disclaimer Notice

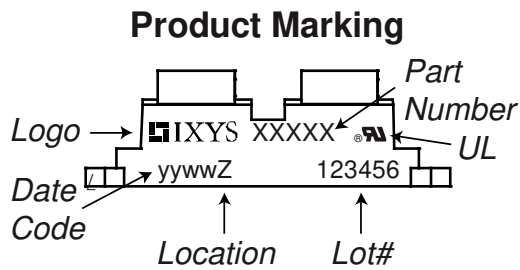
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| Rectifier | | | | Ratings | | | |
|------------|--|---|-------------|------------------------------|------|------|-------------------|
| Symbol | Definition | Conditions | | min. | typ. | max. | Unit |
| V_{RSM} | max. non-repetitive reverse blocking voltage | | | | | 1300 | V |
| V_{RRM} | max. repetitive reverse blocking voltage | | | | | 1200 | V |
| I_R | reverse current | $V_R = 1200\text{ V}$ | | $T_{VJ} = 25^\circ\text{C}$ | | 100 | μA |
| | | $V_R = 1200\text{ V}$ | | $T_{VJ} = 150^\circ\text{C}$ | | 1.5 | mA |
| V_F | forward voltage drop | $I_F = 60\text{ A}$ | | $T_{VJ} = 25^\circ\text{C}$ | | 1.25 | V |
| | | $I_F = 120\text{ A}$ | | | | 1.50 | V |
| | | $I_F = 60\text{ A}$ | | $T_{VJ} = 125^\circ\text{C}$ | | 1.22 | V |
| | | $I_F = 120\text{ A}$ | | | | 1.54 | V |
| I_{FAV} | average forward current | $T_C = 95^\circ\text{C}$ | rectangular | $T_{VJ} = 150^\circ\text{C}$ | | 60 | A |
| V_{F0} | threshold voltage | } for power loss calculation only | | $T_{VJ} = 150^\circ\text{C}$ | | 0.88 | V |
| r_F | slope resistance | | | | | 5.4 | m Ω |
| R_{thJC} | thermal resistance junction to case | | | | | 0.6 | K/W |
| R_{thCH} | thermal resistance case to heatsink | | | | 0.1 | | K/W |
| P_{tot} | total power dissipation | | | $T_C = 25^\circ\text{C}$ | | 210 | W |
| I_{FSM} | max. forward surge current | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | | $T_{VJ} = 45^\circ\text{C}$ | | 800 | A |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | | $V_R = 0\text{ V}$ | | 865 | A |
| | | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | | $T_{VJ} = 150^\circ\text{C}$ | | 680 | A |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | | $V_R = 0\text{ V}$ | | 735 | A |
| I^2t | value for fusing | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | | $T_{VJ} = 45^\circ\text{C}$ | | 3.20 | kA ² s |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | | $V_R = 0\text{ V}$ | | 3.12 | kA ² s |
| | | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | | $T_{VJ} = 150^\circ\text{C}$ | | 2.31 | kA ² s |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | | $V_R = 0\text{ V}$ | | 2.25 | kA ² s |
| C_J | junction capacitance | $V_R = 400\text{ V}; f = 1\text{ MHz}$ | | $T_{VJ} = 25^\circ\text{C}$ | | 27 | pF |



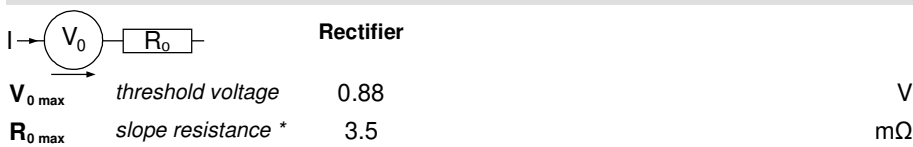
| Package SOT-227B (minibloc) | | | | Ratings | | | |
|-----------------------------|--|----------------------|-------------------------------------|---------|------|------|--|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit | |
| I_{RMS} | RMS current | per terminal | | | 150 | A | |
| T_{VJ} | virtual junction temperature | | -40 | | 150 | °C | |
| T_{op} | operation temperature | | -40 | | 125 | °C | |
| T_{stg} | storage temperature | | -40 | | 150 | °C | |
| Weight | | | | | 30 | g | |
| M_D | mounting torque | | 1.1 | | 1.5 | Nm | |
| M_T | terminal torque | | 1.1 | | 1.5 | Nm | |
| $d_{Spp/App}$ | creepage distance on surface striking distance through air | terminal to terminal | 10.5 | 3.2 | | mm | |
| $d_{Spb/Apb}$ | | terminal to backside | 8.6 | 6.8 | | mm | |
| V_{ISOL} | isolation voltage | t = 1 second | | 3000 | | V | |
| | | t = 1 minute | 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA | 2500 | | V | |



| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DSI2x55-12A | DSI2x55-12A | Tube | 10 | 477052 |

| Similar Part | Package | Voltage class |
|--------------|---------------------|---------------|
| DSI2x55-16A | SOT-227B (minibloc) | 1600 |

Equivalent Circuits for Simulation * on die level $T_{VJ} = 150^{\circ}C$

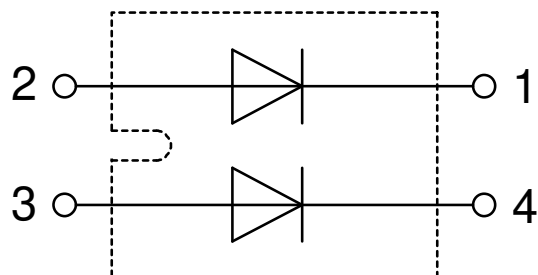




Outlines SOT-227B (minibloc)



| Dim. | Millimeter | | Inches | |
|------|------------|-------|--------|-------|
| | min | max | min | max |
| A | 31.50 | 31.88 | 1.240 | 1.255 |
| B | 7.80 | 8.20 | 0.307 | 0.323 |
| C | 4.09 | 4.29 | 0.161 | 0.169 |
| D | 4.09 | 4.29 | 0.161 | 0.169 |
| E | 4.09 | 4.29 | 0.161 | 0.169 |
| F | 14.91 | 15.11 | 0.587 | 0.595 |
| G | 30.12 | 30.30 | 1.186 | 1.193 |
| H | 37.80 | 38.23 | 1.488 | 1.505 |
| J | 11.68 | 12.22 | 0.460 | 0.481 |
| K | 8.92 | 9.60 | 0.351 | 0.378 |
| L | 0.74 | 0.84 | 0.029 | 0.033 |
| M | 12.50 | 13.10 | 0.492 | 0.516 |
| N | 25.15 | 25.42 | 0.990 | 1.001 |
| O | 1.95 | 2.13 | 0.077 | 0.084 |
| P | 4.95 | 6.20 | 0.195 | 0.244 |
| Q | 26.54 | 26.90 | 1.045 | 1.059 |
| R | 3.94 | 4.42 | 0.155 | 0.167 |
| S | 4.55 | 4.85 | 0.179 | 0.191 |
| T | 24.59 | 25.25 | 0.968 | 0.994 |
| U | -0.05 | 0.10 | -0.002 | 0.004 |
| V | 3.20 | 5.50 | 0.126 | 0.217 |
| W | 19.81 | 21.08 | 0.780 | 0.830 |
| Z | 2.50 | 2.70 | 0.098 | 0.106 |



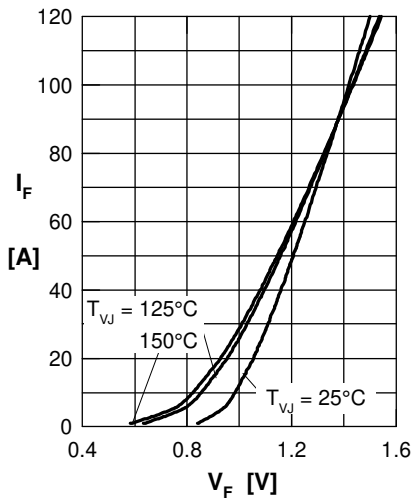
Rectifier


Fig. 1 Forward current versus voltage drop per diode

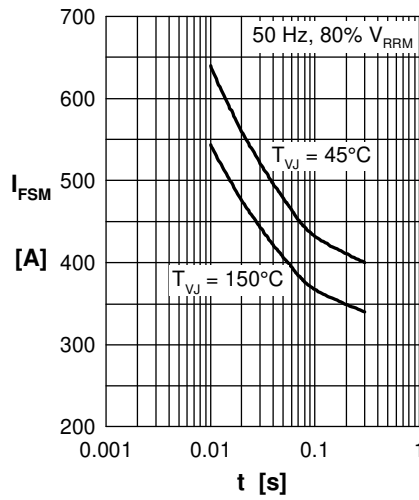


Fig. 2 Surge overload current

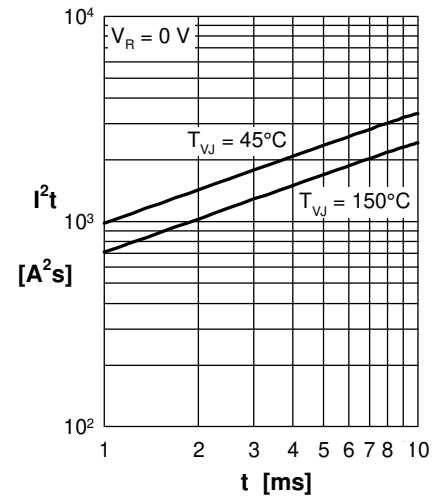
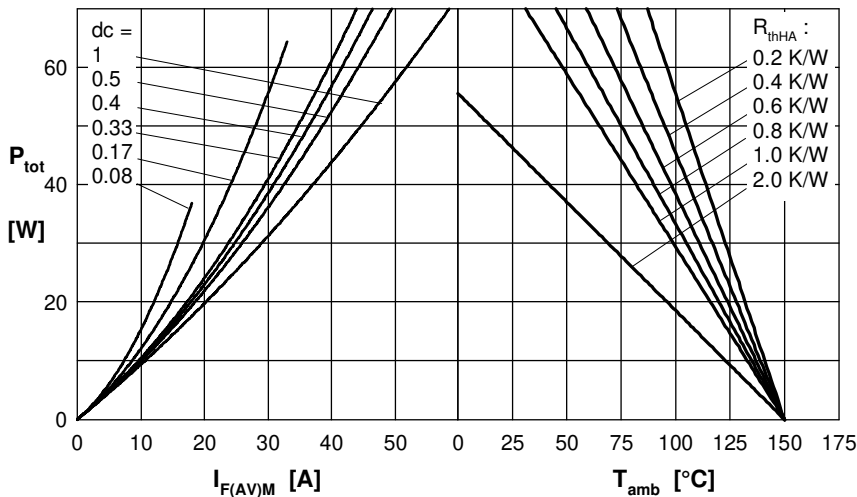

 Fig. 3 I^2t versus time per diode


Fig. 4 Power dissipation vs. direct output current & ambient temperature

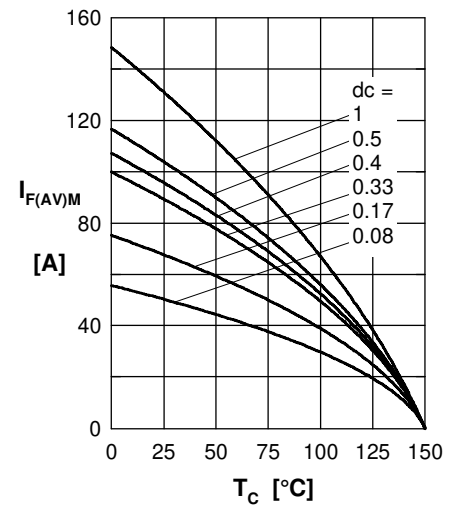


Fig. 5 Max. forward current versus case temperature

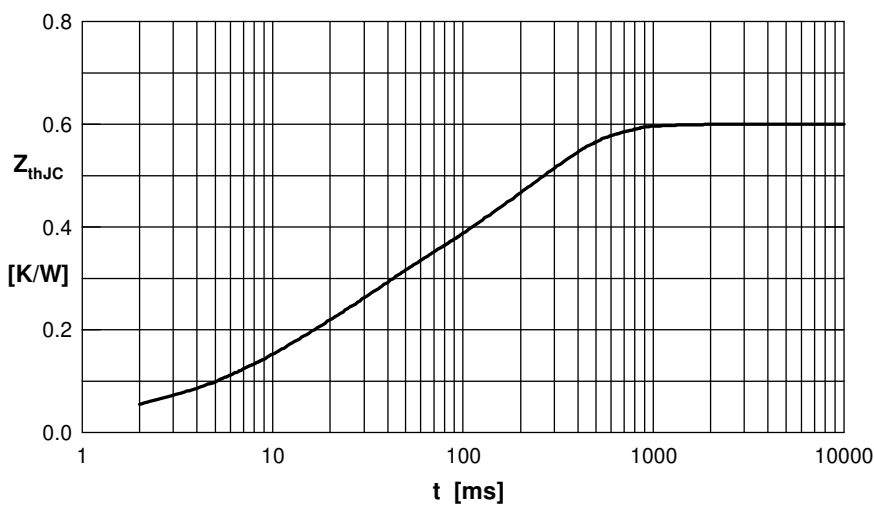


Fig. 6 Transient thermal impedance junction to case

 Constants for Z_{thJC} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.0240 | 0.01000 |
| 2 | 0.0160 | 0.00001 |
| 3 | 0.0500 | 0.00500 |
| 4 | 0.1800 | 0.02300 |
| 5 | 0.3300 | 0.22000 |